

#### Door actuator driver

#### **Features**

- Three half bridges for 1.5A load (R<sub>on</sub>=800mΩ)
- One highside driver for 6A load ( $R_{on}$ =100m $\Omega$ )
- Two highside drivers for 1.5A load (R<sub>on</sub>=800mΩ)
- Programmable softstart function to drive loads with higher inrush currents (i.e. current >6A, >1.5A)
- Very low current consumption in standby mode (I<sub>S</sub> < 6µA typ; T<sub>i</sub> ≤ 85 °C)
- All outputs short circuit protected
- Current monitor output for highside OUT1, OUT4, OUT5 and OUT6
- All outputs over temperature protected
- Open load diagnostic for all outputs
- Overload diagnostic for all outputs
- PWM control of all outputs
- Charge pump output for reverse polarity protection



#### **Applications**

Door actuator driver with bridges for mirror axis control and highside driver for mirror defroster and two 10W-light bulbs.

#### Description

The L9954 and L9954XP are microcontroller driven, multifunctional door actuator drivers for automotive applications. Up to two DC motors and three grounded resistive loads can be driven with three half bridges and three highside drivers. The integrated standard serial peripheral interface (SPI) controls all operation modes (forward, reverse, brake and high impedance). All diagnostic information is available via the SPI.

Table 1. Device summary

Package -	Order codes		
rackaye	Tube	Tape and reel	
PowerSO-36	L9954	L9954TR	
PowerSSO-36	L9954XP	L9954XPTR	

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#### Block diagram and pin description 1

Figure 1. **Block diagram** 

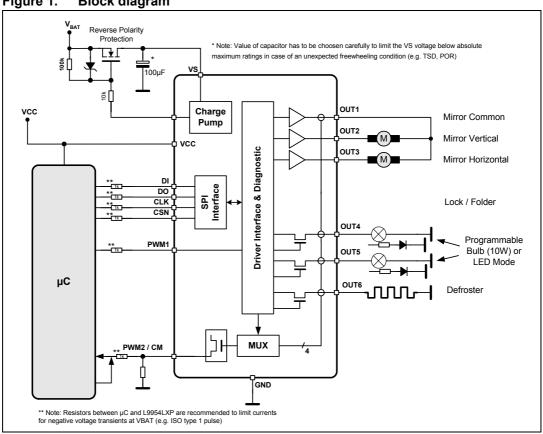


Table 2. Pin definitions and functions

Pin	Symbol	Function	
1, 18, 19, 36	GND	Ground: Reference potential Important: for the capability of driving the full current at the outputs all pins of GND must be externally connected.	
2, 35	OUT6	Highside-driver-output 6 The output is built by a highside switch and is intended for resistive loads, hence the internal reverse diode from GND to the output is missing. For ESD reason a diode to GND is present but the energy which can be dissipated is limited. The highside driver is a power DMOS transistor with an internal parasitic reverse diode from the output to VS (bulk-drain-diode). The output is over-current and open load protected. Important: for the capability of driving the full current at the outputs both pins of OUT6 must be externally connected.	

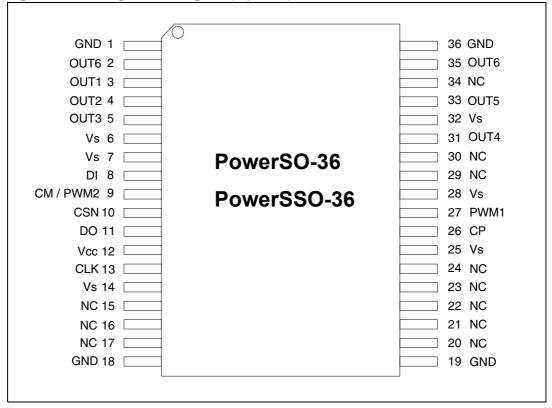
Table 2. Pin definitions and functions (continued)

Pin	Symbol	Function		
3 4 5	OUT1 OUT2 OUT3	Half-bridge-output 1,2,3 The output is built by a highside and a lowside switch, which are internally connected. The output stage of both switches is a power DMOS transistor. Each driver has an internal parasitic reverse diode (bulk-drain-diode: highside driver from output to VS, lowside driver from GND to output). This output is over-current and open load protected.		
6, 7, 14, 25, 28, 32	Vs	Power supply voltage (external reverse protection required) For this input a ceramic capacitor as close as possible to GND is recommended. Important: for the capability of driving the full current at the outputs all pins of VS must be externally connected.		
8	DI	Serial data input The input requires CMOS logic levels and receives serial data from the microcontroller. The data is an 24bit control word and the least significant bit (LSB, bit 0) is transferred first.		
9	CM/PWM2	Current monitor output/PWM2 input  Depending on the selected multiplexer bits of Input Data Register this output sources an image of the instant current through the corresponding highside driver with a ratio of 1/10.000. This pin is bidirectional. The microcontroller can overdrive the current monitor signal to provide a second PWM input for the output OUT5.		
10	CSN	Chip select not input / testmode This input is low active and requires CMOS logic levels. The serial data transfer between L9954 and micro controller is enabled by pulling the input CSN to low level.		
11	DO	Serial data output The diagnosis data is available via the SPI and this tristate-output. The output will remain in tristate, if the chip is not selected by the input CSN (CSN = high)		
12	V <sub>CC</sub>	Logic supply voltage For this input a ceramic capacitor as close as possible to GND is recommended.		
13	CLK	Serial clock input This input controls the internal shift register of the SPI and requires CMOS logic levels.		
26	СР	Charge pump output This output is provided to drive the gate of an external n-channel power MOS used for reverse polarity protection.		
27	PWM1	PWM1 input This input signal can be used to control the drivers OUT1-OUT4 and OUT6 by an external PWM signal.		

Table 2. Pin definitions and functions (continued)

Pin	Symbol	Function	
31 33	OUT4, OUT5	Highside-driver-output 4 and 5 Each output is built by a highside switch and is intended for resistive loads, hence the internal reverse diode from GND to the output is missing. For ESD reason a diode to GND is present but the energy which can be dissipated is limited. Each highside driver is a power DMOS transistor with an internal parasitic reverse diode from each output to VS (bulk-drain-diode). Each output is over-current and open load protected.	
15, 16, 17, 20, 21, 22, 23, 24, 29, 30, 34	NC	Not connected pins.	

Figure 2. Configuration diagram (top view)



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### 2 Electrical specifications

#### 2.1 Absolute maximum ratings

Stressing the device above the rating listed in the "Absolute maximum ratings" table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics SURE Program and other relevant quality document

Table 3. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V.	DC supply voltage	-0.3 to28	V
V <sub>S</sub>	Single pulse t <sub>max</sub> < 400ms	40	V
V <sub>CC</sub>	Stabilized supply voltage, logic supply	-0.3 to 5.5	V
$V_{DI}$ , $V_{DO}$ , $V_{CLK}$ , $V_{CSN}$ , $V_{pwm1}$	Digital input / output voltage	-0.3 to V <sub>CC</sub> + 0.3	V
V <sub>CM</sub>	Current monitor output	-0.3 to V <sub>CC</sub> + 0.3	V
V <sub>CP</sub>	Charge pump output	-25 to V <sub>S</sub> + 11	V
I <sub>OUT1,2,3,4,5</sub>	Output current	±5	Α
I <sub>OUT6</sub>	Output current	±10	Α

### 2.2 ESD protection

Table 4. ESD protection

Parameter	Value	Unit
All pins	± 2 <sup>(1)</sup>	kV
Output pins: OUT1 - OUT6	± 8 <sup>(2)</sup>	kV

<sup>1.</sup> HBM according to MIL 883C, Method 3015.7 or EIA/JESD22-A114-A.

#### 2.3 Thermal data

Table 5. Operating junction temperature

Symbol	Parameter	Value	Unit
Tj	Operating junction temperature	-40 to 150	°C

<sup>2.</sup> HBM with all unzapped pins grounded.

Table 6. Temperature warning and thermal shutdown

Symbol	Parameter		Min.	Тур.	Max.	Unit
T <sub>jTW ON</sub>	Temperature warning threshold junction temperature	Tj	130		150	°C
T <sub>jSD ON</sub>	Thermal shutdown threshold junction temperature	T <sub>j</sub> increasing			170	°C
T <sub>jSD OFF</sub>	Thermal shutdown threshold junction temperature	T <sub>j</sub> decreasing	150			°C
T <sub>jSD HYS</sub>	Thermal shutdown hysteresis			5		°K

#### 2.4 Electrical characteristics

 $V_S$  = 8 to 16V,  $V_{CC}$  = 4.5 to 5.3V,  $T_j$  = - 40 to 150°C, unless otherwise specified. The voltages are referred to GND and currents are assumed positive, when the current flows into the pin.

Table 7. Supply

Symbol	Parameter	Test condition	Min.	Тур.	Max	Unit
V <sub>S</sub>	Operating supply voltage range		7		28	V
	V <sub>S</sub> DC supply current	$V_S = 16V$ , $V_{CC} = 5.3V$ active mode OUT1 - OUT6 floating		7	20	mA
I <sub>S</sub>	V <sub>S</sub> quiescent supply current	$V_S = 16V$ , $V_{CC} = 0V$ standby mode OUT1 - OUT6 floating $T_{test} = -40^{\circ}C$ , 25°C		4	12	μА
		T <sub>test</sub> = 85°C <sup>(1)</sup>		6	25	μΑ
	V <sub>CC</sub> DC supply current	$V_S = 16V$ , $V_{CC} = 5.3V$ CSN = $V_{CC}$ , active mode		1	3	mA
I <sub>CC</sub>	V <sub>CC</sub> quiescent supply current	$V_S = 16V$ , $V_{CC} = 5.3V$ $CSN = V_{CC}$ standby mode OUT1 - OUT6 floating		25	50	μА
l <sub>s</sub> + l <sub>cc</sub>	Sum quiescent supply current	$V_S = 16V$ , $V_{CC} = 5.3V$ $CSN = V_{CC}$ standby mode OUT1 - OUT6 floating $T_{test} = 130^{\circ}C$		50	100	μΑ

<sup>1.</sup> Guaranteed by design.

Table 8. Overvoltage and undervoltage detection

Symbol	Parameter	Test condition	Min.	Тур.	Max	Unit
V <sub>SUV ON</sub>	VS UV-threshold voltage	V <sub>S</sub> increasing	5.7		7.2	V
V <sub>SUV OFF</sub>	VS UV-threshold voltage	V <sub>S</sub> decreasing	5.5		6.9	٧
V <sub>SUV hyst</sub>	VS UV-hysteresis	V <sub>SUV ON</sub> - V <sub>SUV OFF</sub>		0.5		٧
V <sub>SOV OFF</sub>	VS OV-threshold voltage	V <sub>S</sub> increasing	18		24.5	٧
V <sub>SOV ON</sub>	VS OV-threshold voltage	V <sub>S</sub> decreasing	17.5		23.5	٧
V <sub>SOV hyst</sub>	VS OV-hysteresis	V <sub>SOV OFF</sub> - V <sub>SOV ON</sub>		1		٧
V <sub>POR OFF</sub>	Power-On-reset threshold	V <sub>CC</sub> increasing			4.4	٧
V <sub>POR ON</sub>	Power-On-reset threshold	V <sub>CC</sub> decreasing	3.1			V
V <sub>POR hyst</sub>	Power-On-reset hysteresis	V <sub>POR OFF</sub> - V <sub>POR ON</sub>		0.3		٧

Table 9. Current monitor output

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
V <sub>CM</sub>	Functional voltage range	V <sub>CC</sub> = 5V	0		4	V
I <sub>CM,r</sub>	Current monitor output ratio: I <sub>CM</sub> / I <sub>OUT1,4,5,6</sub>	0V ≤ V <sub>CM</sub> ≤ 4V, VCC=5V		1 10.000		
I <sub>CM acc</sub>	Current monitor accuracy	$ \begin{aligned} 0 & V \leq V_{CM} \leq 3.8V, \\ V_{CC} = 5V, & I_{Out,min} = 500 \text{mA}, \\ I_{Out \ max} = 6A \\ (FS = \text{full scale} = 600 \mu\text{A}) \end{aligned} $		4% + 1%FS	8% + 2%FS	

Table 10. Charge pump output

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
V <sub>CP</sub>	Charge pump output voltage	$V_S = 8V$ , $I_{CP} = -60\mu A$	V <sub>S</sub> +6		V <sub>S</sub> +13	V
		$V_S = 10V$ , $I_{CP} = -80\mu A$	V <sub>S</sub> +8		V <sub>S</sub> +13	٧
		$V_S \ge 12V, I_{CP} = -100 \mu A$	V <sub>S</sub> +10		V <sub>S</sub> +13	V
I <sub>CP</sub>	Charge pump output current	$V_{CP} = V_S + 10V, V_S = 13.5V$	95	150	300	μΑ

Table 11. OUT1 - OUT6

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
r <sub>ON OUT1</sub> ,	On-resistance to supply	$V_S = 13.5 \text{ V}, T_j = 25 \text{ °C},$ $I_{OUT1,2,3} = \pm 0.8 \text{A}$		800	1100	mΩ
r <sub>ON OUT2</sub>	or GND	$V_S = 13.5 \text{ V}, T_j = 125 \text{ °C},$ $I_{OUT1,2,3} = \pm 0.8 \text{ A}$		1250	1700	mΩ
r <sub>ON OUT4,</sub> r <sub>ON OUT5</sub>	On-resistance to supply	$V_S = 13.5 \text{ V}, T_j = 25 \text{ °C},$ $I_{OUT4,5} = -0.8 \text{ A}$		500	700	mΩ
		$V_S = 13.5 \text{ V}, T_j = 125 \text{ °C},$ $I_{OUT4,5} = -0.8 \text{ A}$		700	950	mΩ
	On reciptance to cumply	$VS = 13.5 \text{ V}, T_j = 25 \text{ °C},$ $I_{OUT6} = -3 \text{ A}$		100	150	mΩ
<sup>r</sup> on out6	On-resistance to supply	$V_S = 13.5 \text{ V}, T_j = 125 \text{ °C},$ $I_{OUT6} = -3 \text{ A}$		150	200	mΩ
I <sub>ОUТ1</sub> I <sub>ОUТ2</sub> I <sub>ОUТ3</sub>	Output current limitation to GND	Source, V <sub>S</sub> =13.5 V	-3.0		-1.5	Α
I <sub>OUT1</sub> I <sub>OUT2</sub> I <sub>OUT3</sub>	Output current limitation to supply	Sink, V <sub>S</sub> =13.5 V	1.5		3.0	А
I <sub>OUT4</sub> I <sub>OUT5</sub>	Output current limitation to GND	Source, V <sub>S</sub> =13.5 V	-3.0		-1.5	Α
I <sub>OUT6</sub>	Output current limitation to GND	Source, V <sub>S</sub> =13.5 V	-10.5		-6	А
t <sub>d ON H</sub>	Output delay time, highside driver On	V <sub>S</sub> =13.5 V, corresponding lowside driver is not active	20	40	80	μs
t <sub>d OFF H</sub>	Output delay time, highside driver Off	V <sub>S</sub> =13.5 V	50	150	300	μs
t <sub>d ON L</sub>	Output delay time, lowside driver On	V <sub>S</sub> =13.5 V, corresponding highside driver is not active	15	30	70	μs
t <sub>d OFF L</sub>	Output delay time, lowside driver Off	V <sub>S</sub> =13.5 V	80	150	300	μs
t <sub>d HL</sub>	Cross current protection time, source to sink	t <sub>CC ONLS_OFFHS</sub> - t <sub>d</sub> OFF H <sup>(1)</sup>		200	400	μs
t <sub>d LH</sub>	Cross current protection time, sink to source	tcc onhs_offls - td off L(1)		200	400	μs
I <sub>QLH</sub>	Switched-off output current highside drivers of	V <sub>OUT1-6</sub> = 0V, standby mode	0	-2	-5	μΑ
QLI I	OUT1-6	V <sub>OUT1-6</sub> = 0V, active mode	-40	-15	0	μΑ

Table 11. OUT1 - OUT6 (continued)

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
I <sub>QLL</sub>	Switched-off output current lowside drivers of	$V_{OUT1-3}=V_S$ , standby mode	0	80	120	μΑ
	OUT1-3	V <sub>OUT1-3</sub> = V <sub>S</sub> , active mode	-40	-15	0	μΑ
I <sub>OLD123</sub>	Open load detection current of OUT1, OUT2 and OUT3	Source and sink	15	40	60	mA
I <sub>OLD45</sub>	Open load detection current of OUT4 and OUT5	Source and sink	15	40	60	mA
I <sub>OLD6</sub>	Open load detection current of OUT6	Source	30	150	300	mA
t <sub>d OL</sub>	Minimum duration of open load condition to set the status bit		500		3000	μs
t <sub>ISC</sub>	Minimum duration of over-current condition to switch off the driver		10		100	μs
f <sub>rec0</sub>	Recovery frequency for OC recovery duty cycle bit=0		1		4	kHz
f <sub>rec1</sub>	Recovery frequency for OC recovery duty cycle bit=1		2		6	kHz
dV <sub>OUT123</sub> /dt dV <sub>OUT45</sub> /dt	120	$V_S = 13.5 \text{ V}$ $R_{load} = 16.8 \Omega$	0.08	0.2	0.4	V/µs
dV <sub>OUT6</sub> /dt	Slew rate of OUT <sub>6</sub>	$V_S = 13.5 \text{ V}$ $R_{load} = 4.5 \Omega$	0.08	0.2	0.4	V/µs

<sup>1.</sup>  $t_{\text{CC ON}}$  is the switch on delay time  $t_{\text{d ON}}$  if complement in half bridge has to switch Off.

#### 2.5 SPI - electrical characteristics

( $V_S = 8$  to 16V,  $V_{CC} = 4.5$  to 5.3V,  $T_j = -40$  to 150°C, unless otherwise specified. The voltages are referred to GND and currents are assumed positive, when the current flows into the pin).

Table 12. Delay time from standby to active mode

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
t <sub>set</sub>	Delay time	Switching from standby to active mode. Time until output drivers are enabled after CSN going to high.		160	300	μs

Table 13. Inputs: CSN, CLK, PWM1/2 and DI

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
$V_{inL}$	Input low level	V <sub>CC</sub> = 5V	1.5	2.0		V
V <sub>inH</sub>	Input high level	V <sub>CC</sub> = 5V		3.0	3.5	V
V <sub>inHyst</sub>	Input hysteresis	V <sub>CC</sub> = 5V	0.5			٧
I <sub>CSN in</sub>	Pull up current at input CSN	$V_{CSN} = 3.5V V_{CC} = 5V$	-40	-20	-5	μΑ
I <sub>CLK in</sub>	Pull down current at input CLK	V <sub>CLK</sub> = 1.5V	10	25	50	μΑ
I <sub>DI in</sub>	Pull down current at input DI	V <sub>DI</sub> = 1.5V	10	25	50	μΑ
I <sub>PWM1 in</sub>	Pull down current at input PWM1	V <sub>PWM</sub> = 1.5V	10	25	50	μΑ
C <sub>in</sub> <sup>(1)</sup>	Input capacitance at input CSN, CLK, DI and PWM1/2	0 V < V <sub>CC</sub> < 5.3V		10	15	pF

<sup>1.</sup> Value of input capacity is not measured in production test. Parameter guaranteed by design.

Table 14. DI timing <sup>(1)</sup>

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
t <sub>CLK</sub>	Clock period	V <sub>CC</sub> = 5V	1000			ns
t <sub>CLKH</sub>	Clock high time	V <sub>CC</sub> = 5V	400			ns
t <sub>CLKL</sub>	Clock low time	V <sub>CC</sub> = 5V	400			ns
t <sub>set CSN</sub>	CSN setup time, CSN low before rising edge of CLK	V <sub>CC</sub> = 5V	400			ns
t <sub>set CLK</sub>	CLK setup time, CLK high before rising edge of CSN	V <sub>CC</sub> = 5V	400			ns
t <sub>set DI</sub>	DI setup time	V <sub>CC</sub> = 5V	200			ns
t <sub>hold DI</sub>	DI hold time	V <sub>CC</sub> = 5V	200			ns
t <sub>r in</sub>	Rise time of input signal DI, CLK, CSN	V <sub>CC</sub> = 5V			100	ns
t <sub>f in</sub>	Fall time of input signal DI, CLK, CSN	V <sub>CC</sub> = 5V			100	ns

<sup>1.</sup> DI timing parameters tested in production by a passed  $\slash$  failed test:

Tj= -40°C / +25°C: SPI communication @ 2MHz. Tj= +125°C SPI communication @ 1.25 MHz.

Table 15. DO

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
V <sub>DOL</sub>	Output low level	$VCC = 5 \text{ V}, I_D = -2\text{mA}$		0.2	0.4	V
V <sub>DOH</sub>	Output high level	VCC = 5 V, I <sub>D</sub> = 2 mA	V <sub>CC</sub> -0.4	V <sub>CC</sub> -0.2		V

Table 15. DO (continued)

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
I <sub>DOLK</sub>	Tristate leakage current	$V_{CSN} = V_{CC},$ $0V < V_{DO} < V_{CC}$	-10		10	μΑ
C <sub>DO</sub> (1)	Tristate input capacitance	$V_{CSN} = V_{CC},$ $0V < V_{CC} < 5.3V$		10	15	pF

<sup>1.</sup> Value of input capacity is not measured in production test. Parameter guaranteed by design.

Table 16. DO timing

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
t <sub>r DO</sub>	DO rise time	$C_L = 100 \text{ pF}, I_{load} = -1 \text{mA}$		80	140	ns
t <sub>f DO</sub>	DO fall time	$C_L = 100 \text{ pF}, I_{load} = 1\text{mA}$		50	100	ns
t <sub>en DO tri L</sub>	DO enable time from tristate to low level	$C_L$ = 100 pF, $I_{load}$ = 1mA pull-up load to $V_{CC}$		100	250	ns
t <sub>dis DO L tri</sub>	DO disable time from low level to tristate	$C_L$ = 100 pF, $I_{load}$ = 4 mA pull-up load to $V_{CC}$		380	450	ns
t <sub>en DO tri H</sub>	DO enable time from tristate to high level	$C_L = 100 \text{ pF}, I_{load} = -1 \text{mA}$ pull-down load to GND		100	250	ns
t <sub>dis DO H tri</sub>	DO disable time from high level to tristate	C <sub>L</sub> = 100 pF, I <sub>load</sub> = -4mA pull-down load to GND		380	450	ns
t <sub>d DO</sub>	DO delay time	$V_{DO} < 0.3 V_{CC}, V_{DO} > 0.7 V_{CC},$ $C_L = 100 pF$		50	250	ns

Table 17. CSN timing

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
t <sub>CSN_HI,stb</sub>	CSN HI time, switching from standby mode	Transfer of SPI-command to Input Register	20			μs
t <sub>CSN_HI,min</sub>	CSN HI time, active mode	Transfer of SPI-command to input register	4			μs

4

Figure 3. SPI - transfer timing diagram

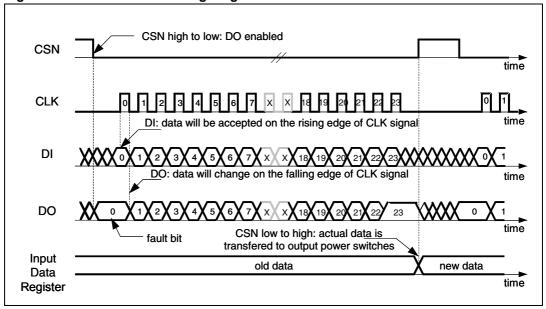
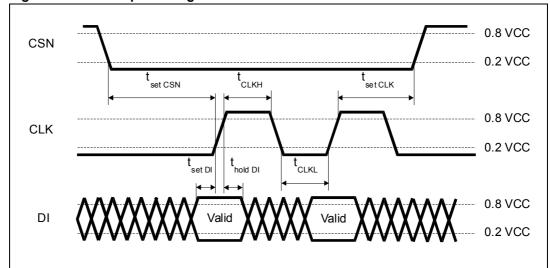


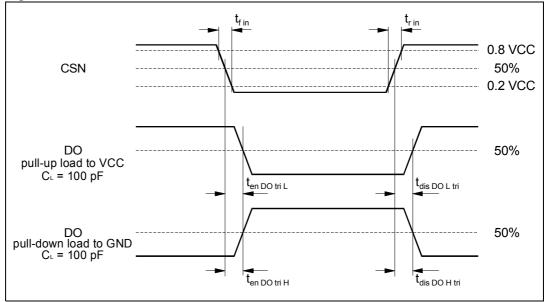
Figure 4. SPI - input timing



 $\mathsf{t}_{\mathsf{fin}}$  $\mathsf{t}_{_{\text{rin}}}$ 0.8 VCC CLK 0.5 VCC 0.2 VCC  $t_{rDO}$ DO 0.8 VCC (low to high) 0.2 VCC t<sub>d DO</sub>|◀  $t_{fDO}$ 0.8 VCC DO (high to low) 0.2 VCC

Figure 5. SPI - DO valid data delay time and valid time





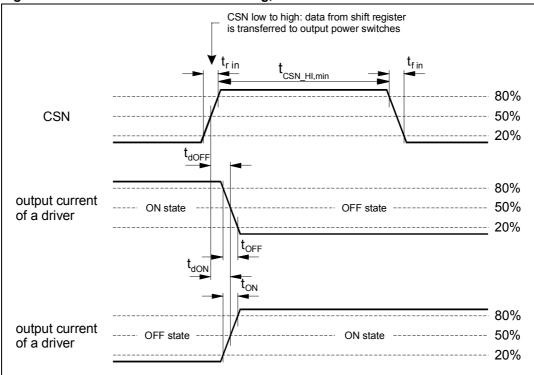
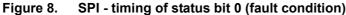
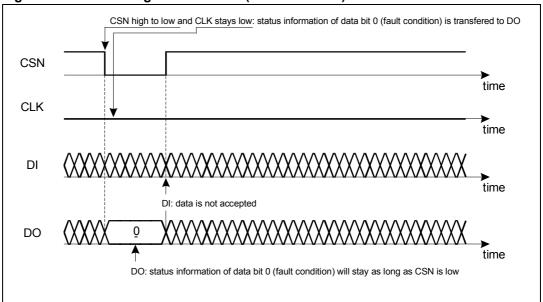


Figure 7. SPI - driver turn on / off timing, minimum CSN HI time





### 3 Application information

#### 3.1 Dual power supply: $V_S$ and $V_{CC}$

The power supply voltage  $V_S$  supplies the half bridges and the highside drivers. An internal charge-pump is used to drive the highside switches. The logic supply voltage  $V_{CC}$  (stabilized 5 V) is used for the logic part and the SPI of the device.

Due to the independent logic supply voltage the control and status information will not be lost, if there are temporary spikes or glitches on the power supply voltage. In case of power-on ( $V_{CC}$  increases from undervoltage to  $V_{POR\ OFF}=4.2\ V$ ) the circuit is initialized by an internally generated power-on-reset (POR). If the voltage  $V_{CC}$  decreases under the minimum threshold ( $V_{POR\ ON}=3.4\ V$ ), the outputs are switched to tristate (high impedance) and the status registers are cleared.

#### 3.2 Standby mode

The standby mode of the L9954 is activated by clearing the bit 23 of the Input Data Register 0. All latched data will be cleared and the inputs and outputs are switched to high impedance. In the standby mode the current at  $V_S$  ( $V_{CC}$ ) is less than 6  $\mu$ A (50 $\mu$ A) for CSN = high (DO in tristate). By switching the  $V_{CC}$  voltage a very low quiescent current can be achieved. If bit 23 is set, the device will be switched to active mode.

#### 3.3 Inductive loads

Each half bridge is built by an internally connected highside and a lowside power DMOS transistor. Due to the built-in reverse diodes of the output transistors, inductive loads can be driven at the outputs OUT1 to OUT3 without external free-wheeling diodes. The highside drivers OUT4 to OUT6 are intended to drive resistive loads. Hence only a limited energy (E<1mJ) can be dissipated by the internal ESD-diodes in freewheeling condition. For inductive loads (L>100 $\mu$ H) an external free-wheeling diode connected to GND and the corresponding output is needed.

### 3.4 Diagnostic functions

All diagnostic functions (over/open load, power supply over-/undervoltage, temperature warning and thermal shutdown) are internally filtered and the condition has to be valid for at least 32 µs (open load: 1ms, respectively) before the corresponding status bit in the status registers will be set. The filters are used to improve the noise immunity of the device. Open load and temperature warning function are intended for information purpose and will not change the state of the output drivers. On contrary, the overload condition will disable the corresponding driver (over-current) and overtemperature will switch off all drivers (thermal shutdown). Without setting the over-current recovery bits in the Input Data register, the microcontroller has to clear the over-current status bits to reactivate the corresponding drivers.

#### 3.5 Overvoltage and undervoltage detection

If the power supply voltage  $V_S$  rises above the overvoltage threshold  $V_{SOV\ OFF}$  (typical 21 V), the outputs OUT1 to OUT6 are switched to high impedance state to protect the load. When the voltage  $V_S$  drops below the undervoltage threshold  $V_{SUV\ OFF}$  (UV-switch-OFF voltage), the output stages are switched to the high impedance to avoid the operation of the power devices without sufficient gate driving voltage (increased power dissipation). If the supply voltage  $V_S$  recovers (register 0: bit 20=0) to normal operating voltage the outputs stages return to the programmed state after at least 32  $\mu$ s.

If the undervoltage/overvoltage recovery disable bit is set, the automatic turn-on of the drivers is deactivated. The microcontroller needs to clear the status bits to reactivate the drivers. It is strongly recommended to set bit 20 to avoid a possible high current oscillation in case of a shorted output to GND and low battery voltage.

### 3.6 Charge pump

The charge pump runs under all conditions in normal mode. In standby the charge pump is out of action.

#### 3.7 Temperature warning and thermal shutdown

If junction temperature rises above  $T_{j\,TW}$  a temperature warning flag is set after at least 32  $\mu s$  and is detectable via the SPI. If junction temperature increases above the second threshold  $T_{j\,SD}$ , the thermal shutdown bit will be set and power DMOS transistors of all output stages are switched off to protect the device after at least 32  $\mu s$ . Temperature warning flag and thermal shutdown bit are latched and must be cleared by the microcontroller. The related bit is only cleared if the temperature decreases below the trigger temperature. If the thermal shutdown bit has been cleared the output stages are reactivated.

### 3.8 Open-load detection

The open load detection monitors the load current in each activated output stage. If the load current is below the open load detection threshold for at least 1 ms ( $t_{dOL}$ ) the corresponding open load bit is set in the status register. Due to mechanical/electrical inertia of typical loads a short activation of the outputs (e.g. 3ms) can be used to test the open load status without changing the mechanical/electrical state of the loads.

#### 3.9 Over load detection

In case of an over-current condition a flag is set in the status register in the same way as open load detection. If the over-current signal is valid for at least  $t_{\rm ISC}=32~\mu s$ , the over-current flag is set and the corresponding driver is switched off to reduce the power dissipation and to protect the integrated circuit. If the over-current recovery bit of the output is zero the microcontroller has to clear the status bits to reactivate the corresponding driver.

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#### 3.10 Current monitor

The current monitor output sources a current image at the current monitor output which has a fixed ratio (1/10000) of the instantaneous current of the selected highside driver. Signal at output CM is blanked after switching on of driver until correct settlement of circuitry (at least for  $32 \mu s$ ).

The bits 18 and 19 of the Input Data Register 0 control which of the outputs OUT1, OUT4, OUT5 and OUT6 will be multiplexed to the current monitor output. The current monitor output allows a more precise analysis of the actual state of the load rather than the detection of an open- or overload condition. For example this can be used to detect the motor state (starting, free-running, stalled). Moreover, it is possible to regulate the power of the defroster more precise by measuring the load current. The current monitor output is bidirectional (c.f. PWM inputs).

#### 3.11 PWM inputs

Each driver has a corresponding PWM enable bit which can be programmed by the SPI interface. If the PWM enable bit in Input Data Register 1 is set , the output is controlled by the logically AND-combination of the PWM signal and the output control bit in Input Data Register 0. The outputs OUT1-OUT4 and OUT6 are controlled by the PWM1 input and the output OUT5 is controlled by the bidirectional input CM/PMW2. For example, the two PWM inputs can be used to dim two lamps independently by external PWM signals.

### 3.12 Cross-current protection

The three half-bridges of the device are cross-current protected by an internal delay time. If one driver (LS or HS) is turned-off the activation of the other driver of the same half bridge will be automatically delayed by the cross-current protection time. After the cross-current protection time is expired the slew-rate limited switch-off phase of the driver will be changed to a fast turn-off phase and the opposite driver is turned-on with slew-rate limitation. Due to this behavior it is always guaranteed that the previously activated driver is totally turned-off before the opposite driver will start to conduct.

# 3.13 Programmable softstart function to drive loads with higher inrush current

Loads with start-up currents higher than the over-current limits (e.g. inrush current of lamps, start current of motors and cold resistance of heaters) can be driven by using the programmable softstart function (i.e. overcurrent recovery mode). Each driver has a corresponding over-current recovery bit. If this bit is set, the device will automatically switch-on the outputs again after a programmable recovery time. The duty cycle in over-current condition can be programmed by the SPI interface to be about 15% ...25%. The PWM modulated current will provide sufficient average current to power up the load (e.g. heat up the bulb) until the load reaches operating condition. The PWM frequency settles at 1.5 kHz or 3 kHz. The device itself cannot distinguish between a real overload and a non linear load like a light bulb. A real overload condition can only be qualified by time. As an example the microcontroller can switch on light bulbs by setting the over-current recovery bit for the first 50ms. After clearing the recovery bit the output will be automatically disabled if the overload condition still exits.

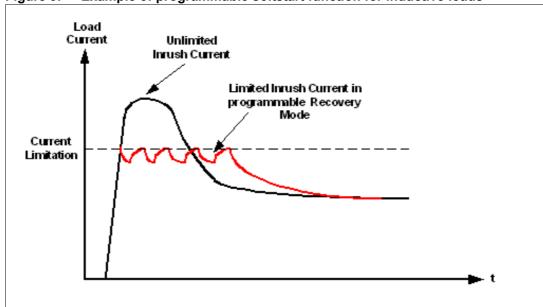


Figure 9. Example of programmable softstart function for inductive loads

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### 4 Functional description of the SPI

#### 4.1 Serial Peripheral Interface (SPI)

This device uses a standard SPI to communicate with a microcontroller. The SPI can be driven by a microcontroller with its SPI peripheral running in following mode: CPOL = 0 and CPHA = 0.

For this mode, input data is sampled by the low to high transition of the clock CLK, and output data is changed from the high to low transition of CLK.

This device is not limited to microcontroller with a build-in SPI. Only three CMOS-compatible output pins and one input pin will be needed to communicate with the device. A fault condition can be detected by setting CSN to low. If CSN = 0, the DO-pin will reflect the status bit 0 (fault condition) of the device which is a logical-or of all bits in the status registers 0 and 1. The microcontroller can poll the status of the device without the need of a full SPI-communication cycle.

Note: In contrast to the SPI-standard the least significant bit (LSB) will be transferred first (see Figure 3).

#### 4.2 Chip Select Not (CSN)

The input pin is used to select the serial interface of this device. When CSN is high, the output pin (DO) will be in high impedance state. A low signal will activate the output driver and a serial communication can be started. The state when CSN is going low until the rising edge of CSN will be called a communication frame. If the CSN-input pin is driven above 7.5V, the L9954 will go into a test mode. In the test mode the DO will go from tri-state to active mode.

### 4.3 Serial Data In (DI)

The input pin is used to transfer data serial into the device. The data applied to the DI will be sampled at the rising edge of the CLK signal and shifted into an internal 24 bit shift register. At the rising edge of the CSN signal the contents of the shift register will be transferred to Data Input Register. The writing to the selected Data Input Register is only enabled if exactly 24 bits are transmitted within one communication frame (i.e. CSN low). If more or less clock pulses are counted within one frame the complete frame will be ignored. This safety function is implemented to avoid an activation of the output stages by a wrong communication frame.

Note: Due to this safety functionality a daisy chaining of SPI is not possible. Instead, a parallel operation of the SPI bus by controlling the CSN signal of the connected ICs is recommended.

### 4.4 Serial Data Out (DO)

The data output driver is activated by a logical low level at the CSN input and will go from high impedance to a low or high level depending on the status bit 0 (fault condition). The first rising edge of the CLK input after a high to low transition of the CSN pin will transfer the

content of the selected status register into the data out shift register. Each subsequent falling edge of the CLK will shift the next bit out.

#### 4.5 Serial clock (CLK)

The CLK input is used to synchronize the input and output serial bit streams. The data input (DI) is sampled at the rising edge of the CLK and the data output (DO) will change with the falling edge of the CLK signal.

#### 4.6 Input data register

The device has two input registers. The first bit (bit 0) at the DI-input is used to select one of the two Input Registers. All bits are first shifted into an input shift register. After the rising edge of CSN the contents of the input shift register will be written to the selected Input Data Register only if a frame of exact 24 data bits are detected. Depending on bit 0 the contents of the selected status register will be transferred to DO during the current communication frame. Bit 1-17 controls the behavior of the corresponding driver.

If bit 23 is zero, the device will go into the standby-mode. The bits 18 and 19 are used to control the current monitor multiplexer. Bit 22 is used to reset all status bits in both status registers. The bits in the status registers will be cleared after the current communication frame (rising edge of CSN).

#### 4.7 Status register

This devices uses two status registers to store and to monitor the state of the device. No error bit (bit 0) is used as a fault bit and is a logical-NOR combination of bits 1-22 in both status registers. The state of this bit can be polled by the microcontroller without the need of a full SPI-communication cycle. If one of the over-current bits is set, the corresponding driver will be disabled. If the over-current recovery bit of the output is not set the microcontroller has to clear the over-current bit to enable the driver. If the thermal shutdown bit is set, all drivers will go into a high impedance state. Again the microcontroller has to clear the bit to enable the drivers.



### 4.8 SPI - Input data and status registers

Table 18. SPI - input data and status registers 0

Bit		registe	r 0 (wri	ite)	Statı	ıs register 0 (read)	
Біі	Name			Comi	ment	Name	Comment
23	Enable bit		device mode. cleared into sta bits are power-	switched If Enabled the deandby received and second	es set the es in active ole Bit is evice goes mode and all ed. After et device dby mode.	Always 1	A broken VCC-or SPI- connection of the L9954 can be detected by the microcontroller, because all 24 bits low or high is not a valid frame.
22	Rese	et bit	status	registe d after r	set both rs will be ising edge of	V <sub>S</sub> overvoltage	In case of an overvoltage or undervoltage event the corresponding bit is set and the outputs are deactivated. If
	OC red			t define nation v	es in vith the over-		VS voltage recovers to normal operating conditions outputs
21	0: 12%	1: 25%	current recovery bit (Input Register 1) the duty cycle in over-current condition of an activated driver.		e duty cycle t condition of	V <sub>S</sub> undervoltage	are reactivated automatically (if Bit 20 of status register 0 is not set).
20	Overvoltage/ Undervoltage recovery disable		microc clear th after un overvo		er has to us register Itage / vent to	Thermal shutdown	In case of a thermal shutdown all outputs are switched off. The microcontroller has to clear the TSD bit by setting the Reset Bit to reactivate the outputs.
19			combir 19 the (1/10.0 HS-out	current 000) of tput will exed to	of bit 18 and t image the selected	Temperature warning	The TW bit can be used for thermal management by the microcontroller to avoid a thermal shutdown. The microcontroller has to clear the TW bit.
	Current		Bit 19	Bit 18	Output		After switching the device from standby mode to active mode
	select bits		0	0	OUT6		an internal timer is started to allow chargepump to settle
			1	0	OUT1		before the outputs can be activated. This bit is cleared
18				1	OUT4	Not ready bit	automatically after start up
			1	1	OUT5		time has finished. Since this bit is controlled by internal clock it
							can be used for synchronizing testing events (e.g. measuring filter times).

Table 18. SPI - input data and status registers 0 (continued)

Bit	Input	register 0 (write)	Statu	us register 0 (read)
ы	Name	Comment	Name	Comment
17	OUT6 – HS on/off		OUT6 – HS over-current	
16	x (don't care)		0	
15	OUT5 – HS on/off		OUT5 – HS over-current	
14	OUT4 – HS on/off	If a bit is set the selected	OUT4 – HS over-current	
13	x (don't care)	output driver is switched	0	In case of an over-current event the corresponding status
12	x (don't care)	on. If the corresponding PWM enable bit is set	0	bit is set and the output driver
11	x (don't care)	(Input Register 1) the	0	is disabled. If the over-current Recovery Enable bit is set
10	x (don't care)	driver is only activated if PWM1 (PWM2) input	0	(Input Register 1) the output
9	x (don't care)	signal is high. The outputs	0	will be automatically reactivated after a delay time
8	x (don't care)	of OUT1-OUT3 are half bridges. If the bits of HS- and LS-driver of the same half bridge are set, the internal logic prevents that both drivers of this output stage can be switched on simultaneously in order to	0	resulting in a PWM modulated
7	x (don't care)		0	current with a programmable duty cycle (Bit 21).
6	OUT3 – HS on/off		OUT3 – HS over-current	If the over-current recovery bit
5	OUT3 – LS on/off		OUT3 – LS over-current	is not set the microcontroller has to clear the over-current bit (Reset Bit) to reactivate the
4	OUT2 – HS on/off	avoid a high internal current from VS to GND.	OUT2 – HS over-current	output driver.
3	OUT2 – LS on/off		OUT2 – LS over-current	
2	OUT1 – HS on/off		OUT1 – HS over-current	
1	OUT1 – LS on/off		OUT1 – LS over-current	
0		0	No error bit	A logical NOR-combination of all bits 1 to 22 in both status registers.

Table 19. SPI - input data and status registers 1

Bit	Inp	ut register 1 (write)	Status re	egister 1 (read)
ы	Name	Comment	Name	Comment
23	Enable bit	If Enable bit is set the device will be switched in active mode. If Enable Bit is cleared device goes into standby mode and all bits are cleared. After poweron reset device starts in standby mode.	Always 1	A broken VCC-or SPI- connection of the L9954 can be detected by the microcontroller, because all 24 bits low or high is not a valid frame.
22	OUT6 OC Recovery Enable		VS overvoltage	In case of an overvoltage or undervoltage event the corresponding bit is
21	x (don't care)	In case of an over-current event the over-current status bit (Status Register 0) is set and the output is switched off. If the over-current Recovery Enable bit is set the output will be automatically reactivated after a delay time resulting in a PWM modulated current with a programmable duty cycle (Bit 21 of Input Data Register 0). Depending on occurrence of Overcurrent Event and internal clock phase it is possible that one recovery cycle is executed even if this bit is set to zero.	VS undervoltage	set and the outputs are deactivated. If Vs voltage recovers to normal operating conditions outputs are reactivated automatically.
20	OUT5 OC Recovery Enable		Thermal shutdown	In case of a thermal shutdown all outputs are switched off. The microcontroller has to clear the TSD bit by setting the Reset Bit to reactivate the outputs.
19	OUT4 OC Recovery Enable		Temperature warning	The TW bit can be used for thermal management by the microcontroller to avoid a thermal shutdown. The microcontroller has to clear the TW bit.
18	x (don't care)		Not ready bit	After switching the device from standby mode to active mode an internal timer is started to allow chargepump to settle before the outputs can be activated. This bit is only present during start up time.  Since this bit is controlled by internal clock it can be used for synchronizing testing events(e.g. measuring filter times).

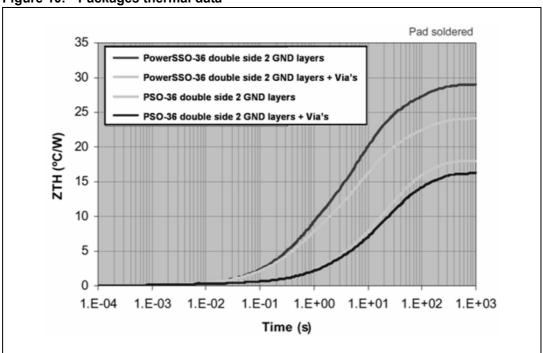
Table 19. SPI - input data and status registers 1 (continued)

Bit	Inp	ut register 1 (write)	Status r	egister 1 (read)
DIL	Name	Comment	Name	Comment
17	x (don't care)		OUT6 – HS open load	
16	x (don't care)		0	
15	x (don't care)		OUT5 – HS open load	
14	OUT3 OC Recovery Enable	After 50ms the bit can be cleared. If over-current condition still exists, a wrong load can be assumed.	OUT4 – HS open load	
13	OUT2 OC Recovery Enable		0	The open load detection monitors the load current
12	OUT1 OC Recovery Enable		0	in each activated output stage. If the load current is below the open load
11	OUT6 PWM1 Enable		0	detection threshold for at least 1 ms (t <sub>dOL</sub> ) the
10	x (don't care)		0	corresponding open load bit is set. Due to
9	OUT5 PWM2 Enable		0	mechanical/electrical inertia of typical loads a
8	OUT4 PWM1 Enable		0	short activation of the outputs (e.g. 3ms) can
7	x (don't care)	If the PWM1/2 Enable Bit is set and the output is enabled	0	be used to test the open load status without
6	x (don't care)	(Input Register 0) the output is switched on if PWM1/2 input is	OUT3 – HS open load	changing the mechanical/electrical
_	/-124>	high and switched off if PWM1/2 input is low. OUT5 is	OUT3 – LS	state of the loads.
5	x (don't care)	controlled by PWM2 input. All	open load	
4	x (don't care)	other outputs are controlled by PWM1 input.	OUT2 -HS open load	
3	OUT3 PWM1 Enable		OUT2- LS open load	
2	OUT2 PWM1 Enable		OUT1 – HS open load	-
1	OUT1 PWM1 Enable		OUT1 - LS open load	-
0		1	No Error bit	A logical NOR-combination of all bits 1 to 22 in both status registers.

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# 5 Packages thermal data





### 6 Package and packing information

# 6.1 ECOPACK® packages

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>.

ECOPACK® is an ST trademark.

### 6.2 PowerSO-36™ package information

Figure 11. PowerSO-36™ package dimensions

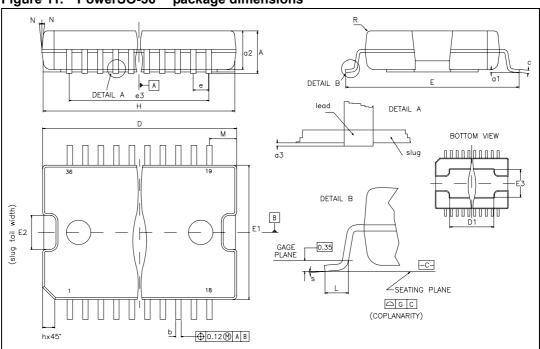


Table 20. PowerSO-36™ mechanical data

Coursele ed		Millimeters	
Symbol	Min.	Тур.	Max.
A			3.60
a1	0.10		0.30
a2			3.30
a3	0		0.10
b	0.22		0.38
С	0.23		0.32
D *	15.80		16.00
D1	9.40		9.80
E	13.90		14.5
E1 *	10.90		11.10
E2			2.90
E3	5.80		6.20
е		0.65	
e3		11.05	
G	0		0.10
Н	15.50		15.90
h			1.10
L	0.8		1.10
М			
N			10 deg
R			
S			8 deg

# 6.3 PowerSSO-36™ package information

Figure 12. PowerSSO-36™ package dimensions

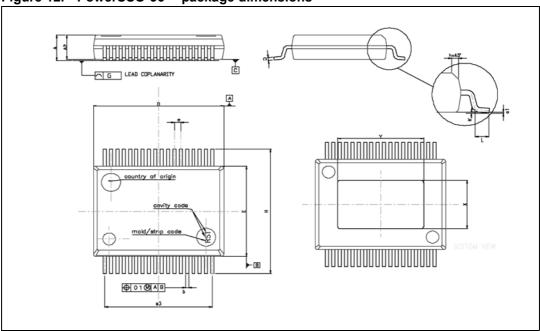


Table 21. PowerSSO-36™ mechanical data

Symbol		Millimeters	
Symbol	Min.	Тур.	Max.
Α	-	-	2.45
A2	2.15	-	2.35
a1	0	-	0.1
b	0.18	-	0.36
С	0.23	-	0.32
D *	10.10	-	10.50
E*	7.4	-	7.6
е	-	0.5	-
e3	-	8.5	-
F	-	2.3	-
G	-	-	0.1
G1	-	-	0.06
Н	10.1	-	10.5
h	-	-	0.4
k	0°	-	8°
L	0.55	-	0.85
N	-	-	10 deg

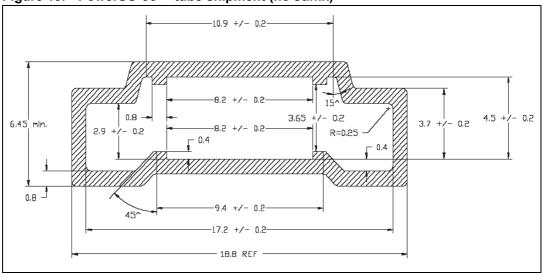
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Table 21. PowerSSO-36™ mechanical data (continued)

Symbol	Millimeters			
	Min.	Тур.	Max.	
Х	4.3	-	5.2	
Y	6.9	-	7.5	

### 6.4 PowerSO-36™ packing information

Figure 13. PowerSO-36<sup>TM</sup> tube shipment (no suffix)



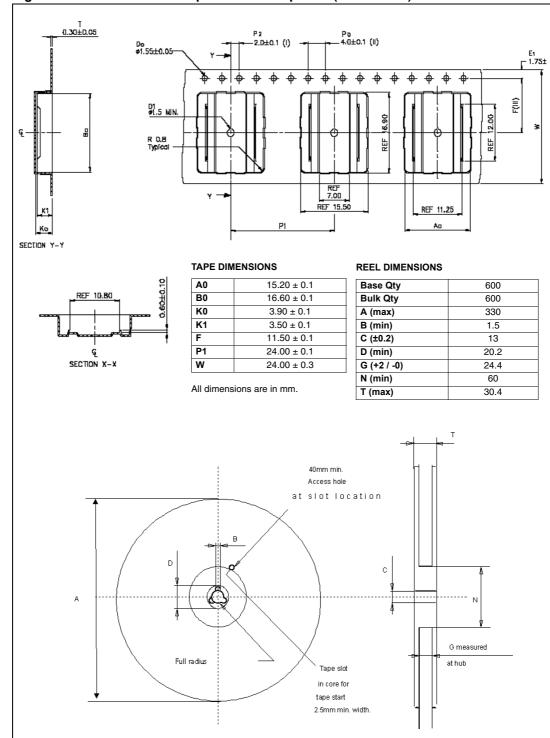


Figure 14. PowerSO-36<sup>TM</sup> tape and reel shipment (suffix "TR")



### 6.5 PowerSSO-36™ packing information

Figure 15. PowerSSO-36<sup>TM</sup> tube shipment (no suffix)

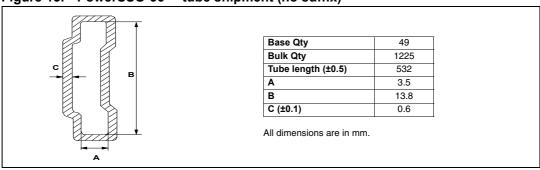
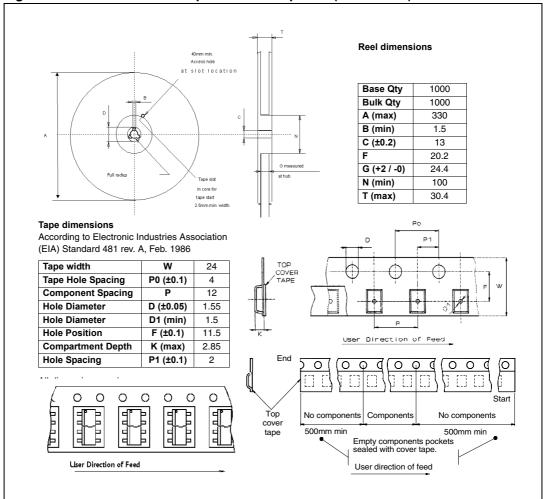


Figure 16. PowerSSO-36<sup>TM</sup> tape and reel shipment (suffix "TR")



Revision history L9954 / L9954XP

# 7 Revision history

Table 22. Document revision history

Date	Revision	Description of changes
23-Jan-2008	1	Initial release.
24-Jun-2009	2	Table 21: PowerSSO-36™ mechanical data:  - Deleted A (min) value  - Changed A (max) value from 2.47 to 2.45  - Changed A2 (max) value from 2.40 to 2.35  - Changed a1 (max) value from 0.075 to 0.1  - Added F and k rows
17-May-2010 3		<ul> <li>Table 21: PowerSSO-36™ mechanical data:</li> <li>Changed X: minimum value from 4.1 to 4.3 and maximum value from 4.7 to 5.2</li> <li>Changed Y: minimum value from 6.5 to 6.9 and maximum value from 7.1 to 7.5</li> </ul>

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